

SLPS199A - AUGUST 2009 - REVISED APRIL 2010

N-Channel NexFET[™] Power MOSFET

Check for Samples: CSD16413Q5A

FEATURES

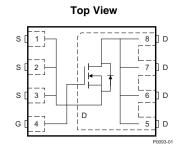
- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5mm × 6mm Plastic Package

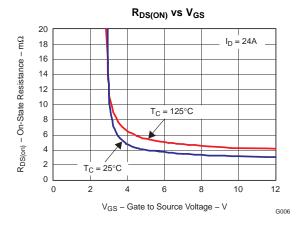
APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Control or Synchronous FET Applications

DESCRIPTION

The NexFET[™] power MOSFET has been designed to minimize losses in power conversion applications.





PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 25			V
Qg	Gate Charge Total (4.5V)	9		nC
Q _{gd}	Gate Charge Gate to Drain	2.5		nC
D	Droin to Source On Desistance	$V_{GS} = 4.5V$	4.1	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V$	3.1	mΩ
V _{GS(th)}	Threshold Voltage	1.6		V

ORDERING INFORMATION

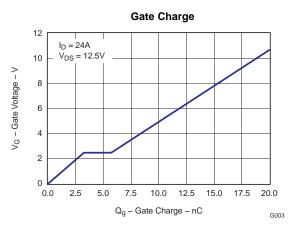
Device	Package	Media	Qty	Ship
CSD16413Q5A	SON 5 × 6 Plastic Package	13-inch reel	2500	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	25	V
V _{GS}	Gate to Source Voltage	+16 / -12	V
	Continuous Drain Current, T _C = 25°C	100	А
ID	Continuous Drain Current ⁽¹⁾	24	А
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	156	А
PD	Power Dissipation ⁽¹⁾	3.1	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, single pulse $I_D = 46A$, L = 0.1mH, $R_G = 25\Omega$	106	mJ

(1) $R_{\theta JA} = 41^{\circ}C/W$ on $1in^2$ Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width $\leq 300 \mu s$, duty cycle $\leq 2\%$



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NexFET is a trademark of Texas Instruments. SLPS199A-AUGUST 2009-REVISED APRIL 2010

www.ti.com



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	haracteristics				¥	
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{D} = 250\mu A$	25			V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 20V$			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +16/-12V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.2	1.6	1.9	V
D	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 24A$		4.1	5.6	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 10V, I_{D} = 24A$		3.1	3.9	mΩ
g _{fs}	Transconductance	$V_{DS} = 15V, I_{D} = 24A$		95		S
Dynamic	Characteristics	· · · · · · · · · · · · · · · · · · ·				
C _{ISS}	Input Capacitance			1370	1780	pF
C _{OSS}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 12.5V f = 1MHz$		1060	1380	pF
C _{RSS}	Reverse Transfer Capacitance			84	109	pF
R _g	Series Gate Resistance			0.9	1.8	Ω
Qg	Gate Charge Total (4.5V)			9	11.7	nC
Q _{gd}	Gate Charge Gate to Drain	V 12 5V 1 24A		2.5		nC
Q _{gs}	Gate Charge Gate to Source	V _{DS} = 12.5V, I _D = 24A		3.5		nC
Qg(th)	Gate Charge at Vth			2.2		nC
Q _{OSS}	Output Charge	$V_{DS} = 13.1V, V_{GS} = 0V$		21		nC
t _{d(on)}	Turn On Delay Time			9.1		ns
t _r	Rise Time	V _{DS} = 12.5V, V _{GS} = 4.5V I _D = 24A		15.9		ns
t _{d(off)}	Turn Off Delay Time	$R_G = 5\Omega$		10.7		ns
t _f	Fall Time			5.7		ns
Diode Cl	haracteristics				¥	
V _{SD}	Diode Forward Voltage	$I_{S} = 24A, V_{GS} = 0V$		0.85	1	V
Q _{rr}	Reverse Recovery Charge	$V_{DD} = 13.1V, I_F = 24A, di/dt = 300A/\mu s$		32		nC
t _{rr}	Reverse Recovery Time	V _{DD} = 13.1V, I _F = 24A, di/dt = 300A/µs		28		ns

THERMAL CHARACTERISTICS

($T_A = 25^{\circ}C$ unless otherwise stated)

	PARAMETER	MIN	TYP	MAX	UNIT
R $_{\theta JC}$	Thermal Resistance Junction to Case ⁽¹⁾			2.6	°C/W
R $_{\theta JA}$	Thermal Resistance Junction to Ambient ⁽¹⁾ ⁽²⁾			51	°C/W

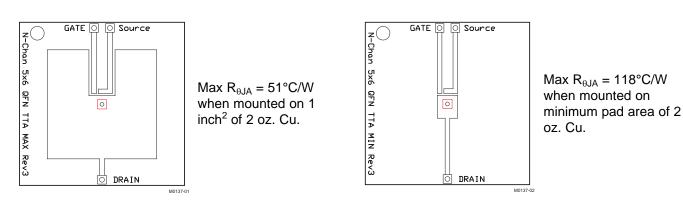
(1) $R_{\theta JC}$ is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 x 1.5 in .060 inch thick FR4 board. $R_{\theta JC}$ is specified by design while $R_{\theta JA}$ is determined by the user's board design.

(2) Device mounted on FR4 Material with 1 inch² of 2 oz. Cu.



CSD16413Q5A

SLPS199A - AUGUST 2009 - REVISED APRIL 2010



TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

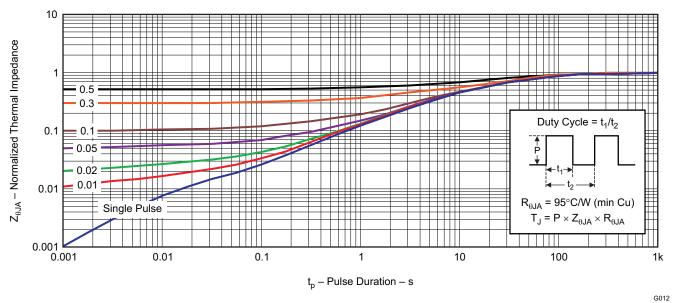
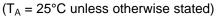


Figure 1. Transient Thermal Impedance







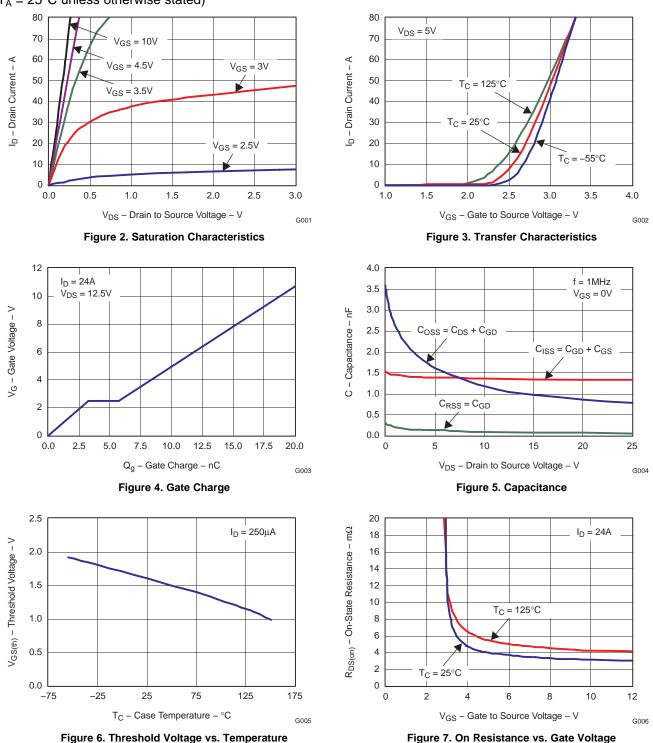
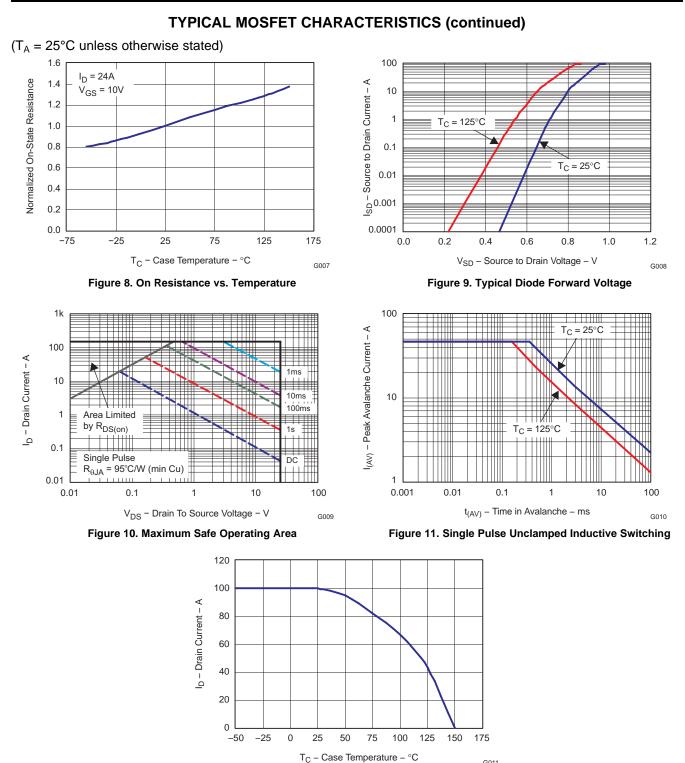


Figure 7. On Resistance vs. Gate Voltage



SLPS199A-AUGUST 2009-REVISED APRIL 2010



G011

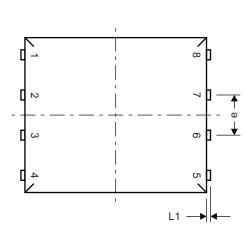
Figure 12. Maximum Drain Current vs. Temperature

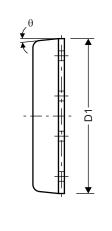
TEXAS INSTRUMENTS

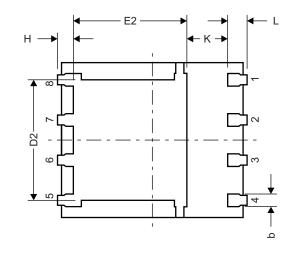
www.ti.com

MECHANICAL DATA

Q5A Package Dimensions



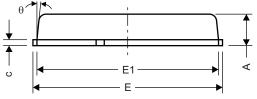




Top View

Side View

Bottom View



Front View

M0135-01

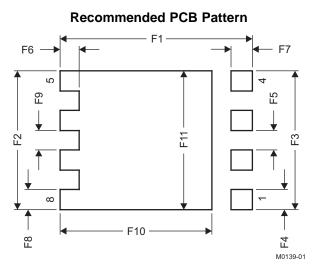
DIM		MILLIMETERS							
	MIN	NOM	MAX						
А	0.90	1.00	1.10						
b	0.33	0.41	0.51						
С	0.20	0.25	0.30						
D1	4.80	4.90	5.00						
D2	3.61	3.81	3.96						
E	5.90	6.00	6.10						
E1	5.70	5.75	5.80						
E2	3.38	3.58	3.78						
е	1.27 BSC								
Н	0.41	0.51	0.61						
К	1.10								
L	0.51	0.61	0.71						
L1	0.06	0.13	0.20						
θ	0°		12°						



CSD16413Q5A

www.ti.com

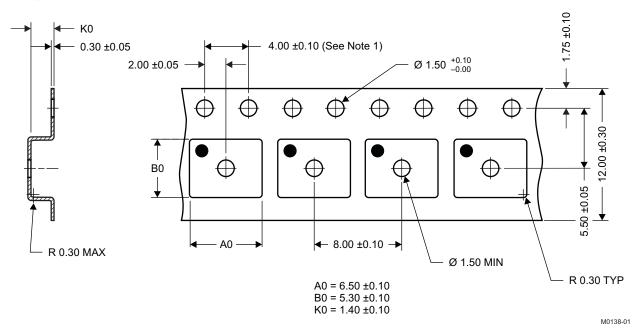
SLPS199A - AUGUST 2009 - REVISED APRIL 2010



DIM	MILLIM	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
F1	6.205	6.305	0.244	0.248	
F2	4.46	4.56	0.176	0.18	
F3	4.46	4.56	0.176	0.18	
F4	0.65	0.7	0.026	0.028	
F5	0.62	0.67	0.024	0.026	
F6	0.63	0.68	0.025	0.027	
F7	0.7	0.8	0.038	0.031	
F8	0.65	0.7	0.026	0.028	
F9	0.62	0.67	0.024	0.026	
F10	4.9	5	0.193	0.197	
F11	4.46	4.56	0.176	0.18	

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible

SLPS199A - AUGUST 2009-REVISED APRIL 2010

REVISION HISTORY

Cł	hanges from Original (August 2009) to Revision A	Page
•	Deleted the Package Marking Information section	7



www.ti.com

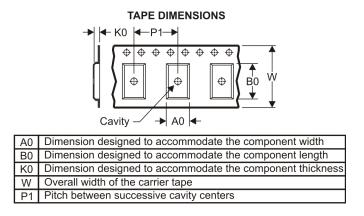
PACKAGE MATERIALS INFORMATION

www.ti.com

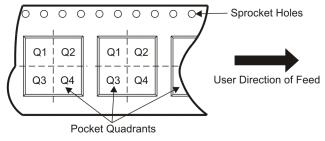
Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16413Q5A	SON	DQJ	8	2500	330.2	12.4	6.5	5.3	1.4	8.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

7-Apr-2011



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16413Q5A	SON	DQJ	8	2500	347.0	342.0	55.0

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps
RF/IF and ZigBee® Solutions	www.ti.com/lprf		

TI E2E Community Home Page

e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated